



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SB1121 / ~~2SD1621~~ — PNP / ~~NPN~~ Epitaxial Planar Silicon Transistors High-Current Driver Applications

### Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment.

### Features

- Adoption of FBET, MBIT processes.
- Low collector-to-emitter saturation voltage.
- Large current capacity and wide ASO.
- Fast switching speed.
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's.

### Specifications ( ) : 2SB1121

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)30	V
Collector-to-Emitter Voltage	VCEO		(-)25	V
Emitter-to-Base Voltage	VEBO		(-)6	V
Collector Current	IC		(-)2	A
Collector Current (Pulse)	ICP		(-)5	A
Collector Dissipation	PC		500	mW
		Mounted on a ceramic board (250mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Marking 2SB1121 : BD

~~2SD1621 : DD~~

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**SANYO Semiconductor Co., Ltd.**

<http://semicon.sanyo.com/en/network>

# 2SB1121 / 2SD1621

## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = (-)20V, I_E = 0A$			(-)0.1	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = (-)4V, I_C = 0A$			(-)0.1	$\mu A$
DC Current Gain	$h_{FE1}$	$V_{CE} = (-)2V, I_C = (-)100mA$	100*		560*	
	$h_{FE2}$	$V_{CE} = (-)2V, I_C = (-)1.5A$	65			
Gain-Bandwidth Product	$f_T$	$V_{CE} = (-)10V, I_C = (-)50mA$		150		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = (-)10V, f = 1MHz$		(32)19		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)1.5A, I_B = (-)75mA$		(-0.35)0.18	(-0.6)0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1.5A, I_B = (-)75mA$		(-0.85)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0A$	(-)30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)25			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0A$	(-)6			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		(60)60		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		(350)550		ns
Fall Time	$t_f$	See specified Test Circuit.		(25)25		ns

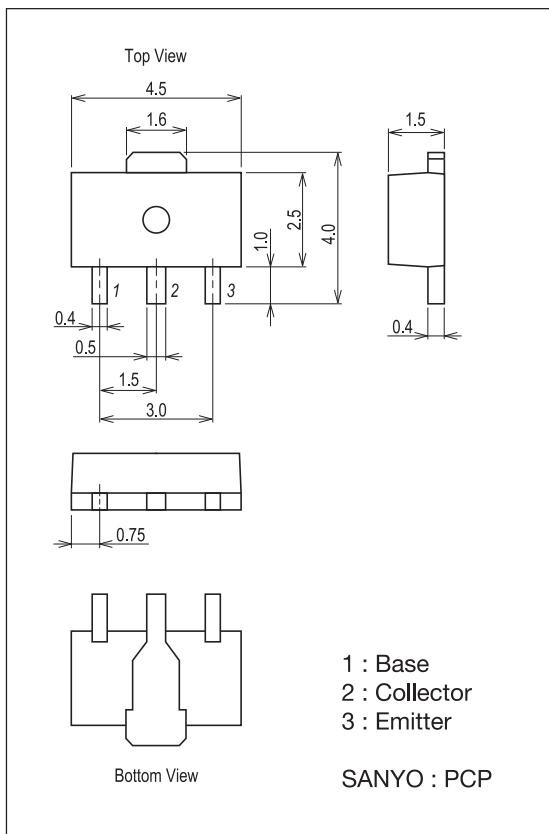
\*: The 2SB1121 / 2SD1621 are classified by 100mA  $h_{FE}$  as follows:

Rank	R	S	T	U
$h_{FE}$	100 to 200	140 to 280	200 to 400	280 to 560

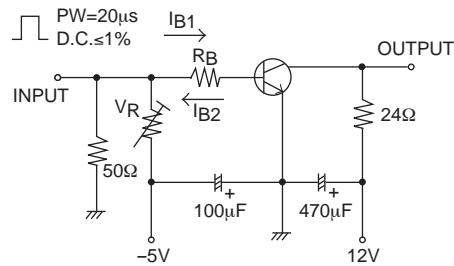
## Package Dimensions

unit : mm (typ)

7007B-004

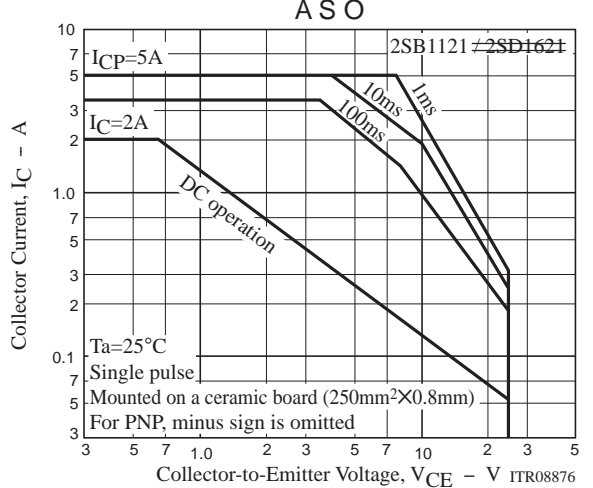
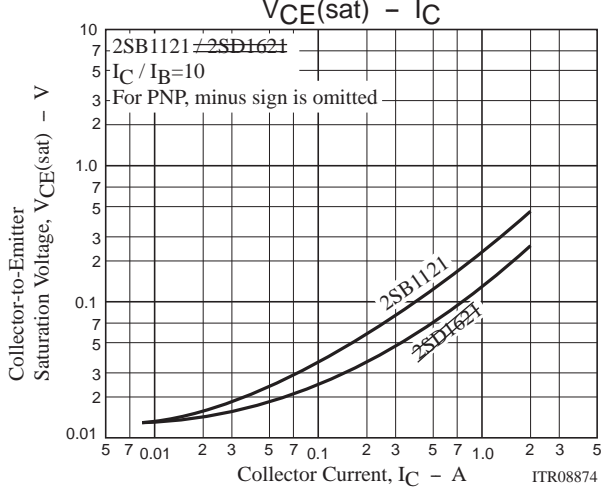
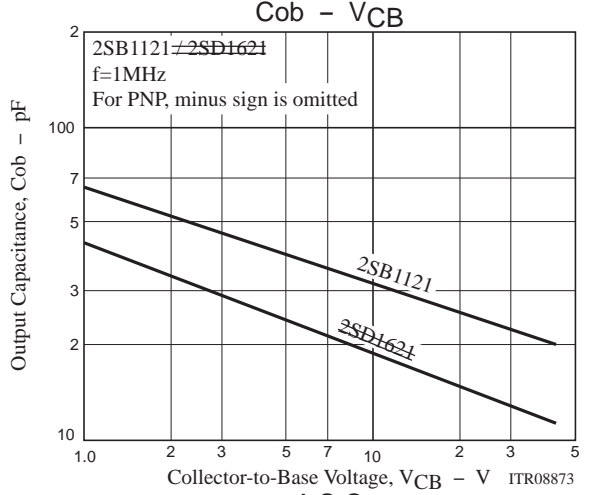
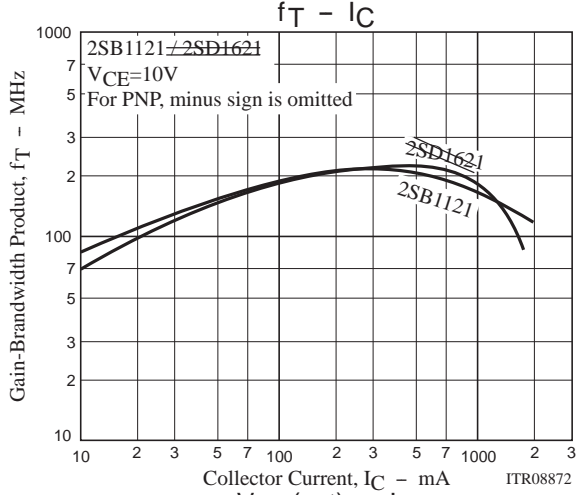
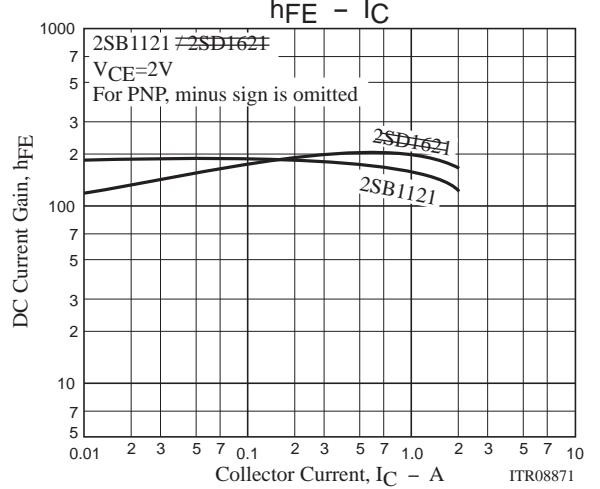
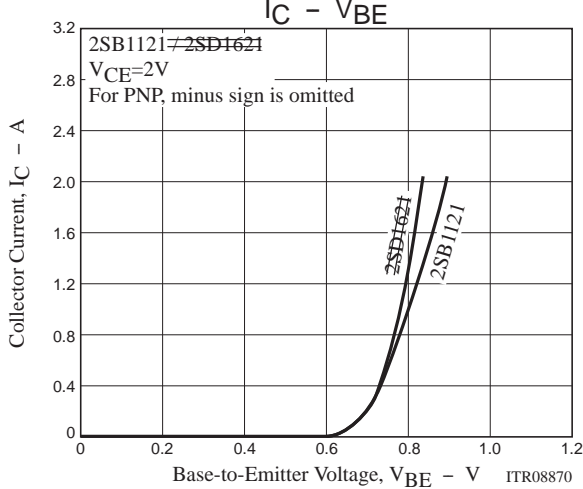
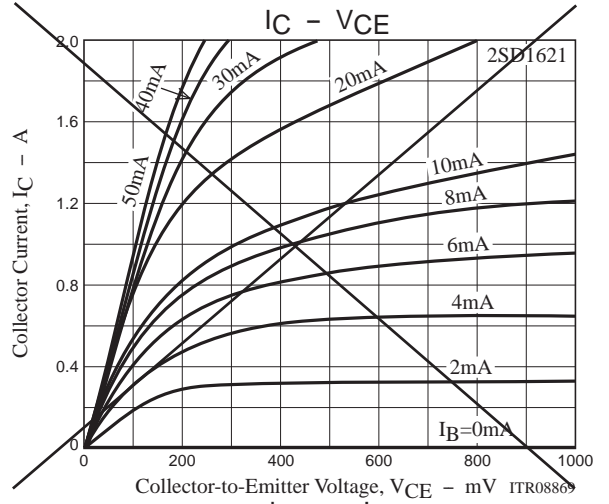
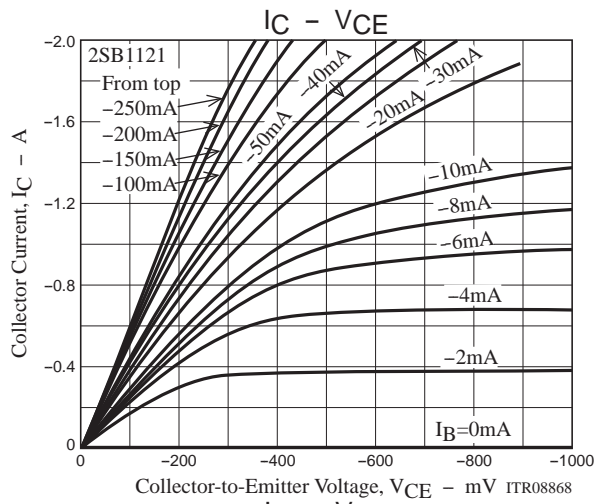


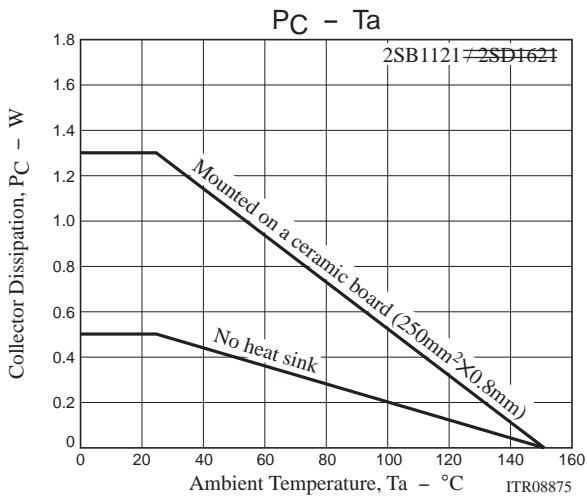
## Switching Time Test Circuit



$I_C = 20I_{B1} = -20I_{B2} = 500mA$   
(For PNP, the polarity is reversed)

# 2SB1121 / 2SD1621





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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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